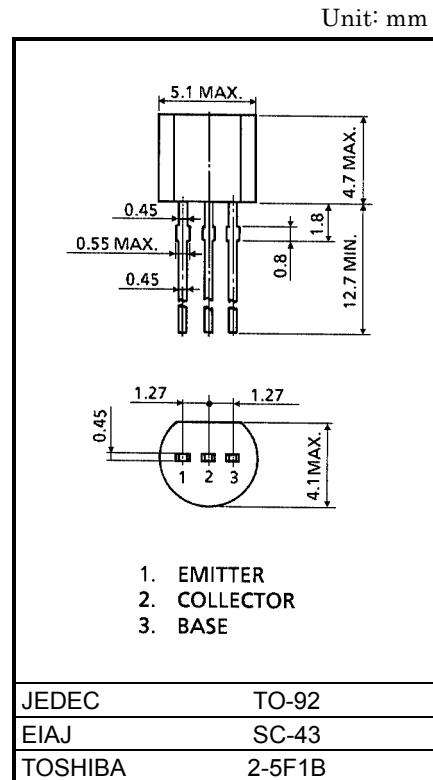


TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

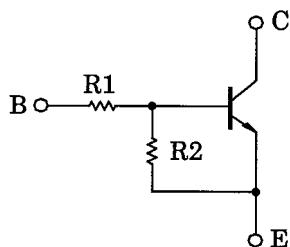
**RN1001, RN1002, RN1003
RN1004, RN1005, RN1006**

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2001~RN2006



Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1001	4.7	4.7
RN1002	10	10
RN1003	22	22
RN1004	47	47
RN1005	2.2	47
RN1006	4.7	47

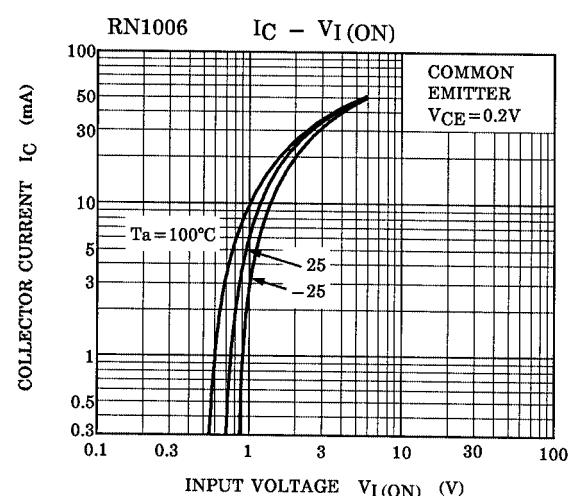
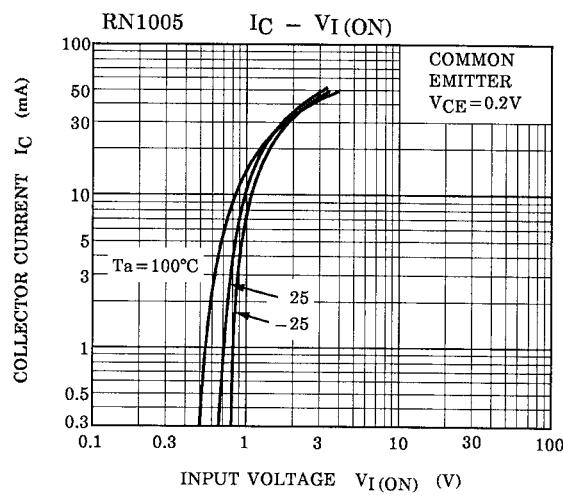
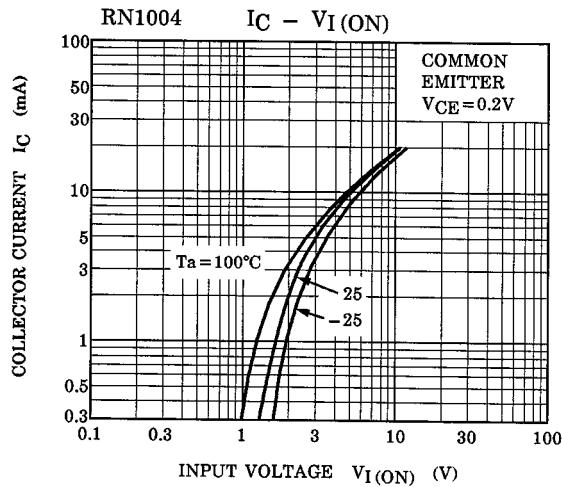
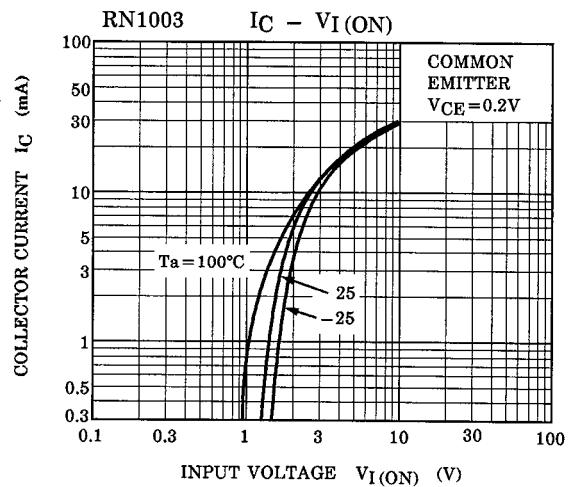
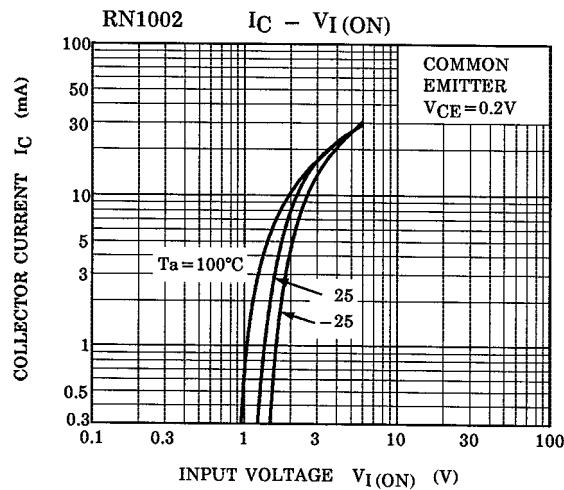
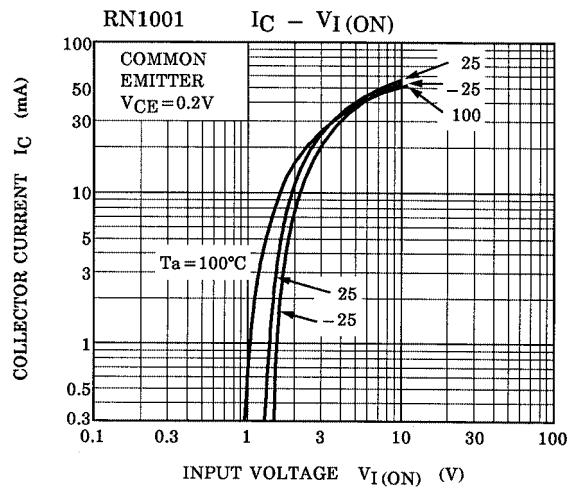
Maximum Ratings (Ta = 25°C)

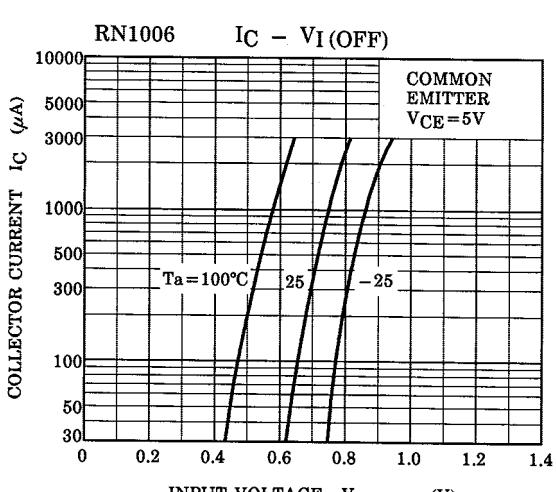
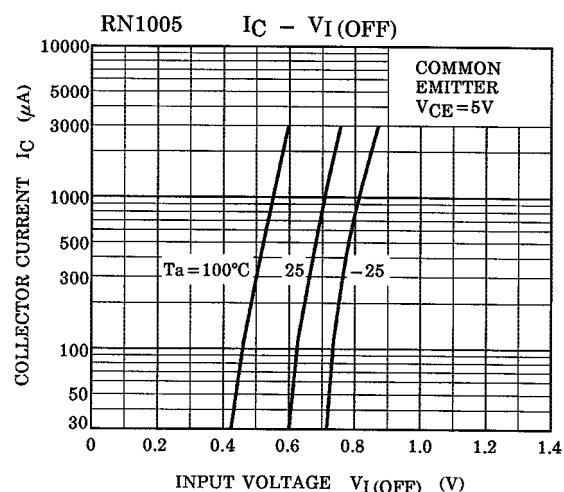
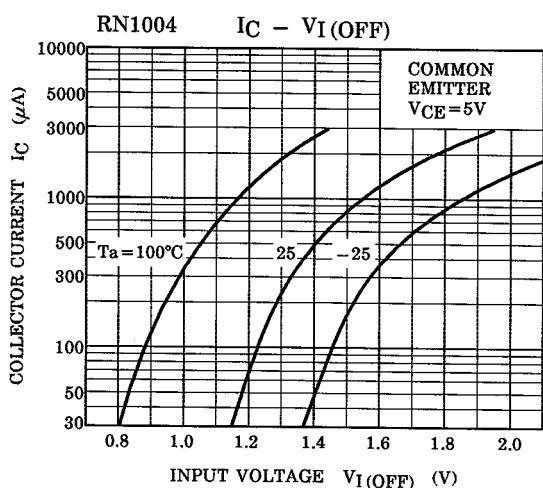
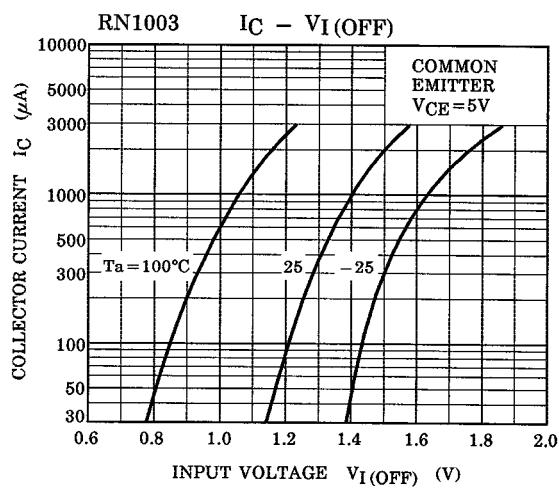
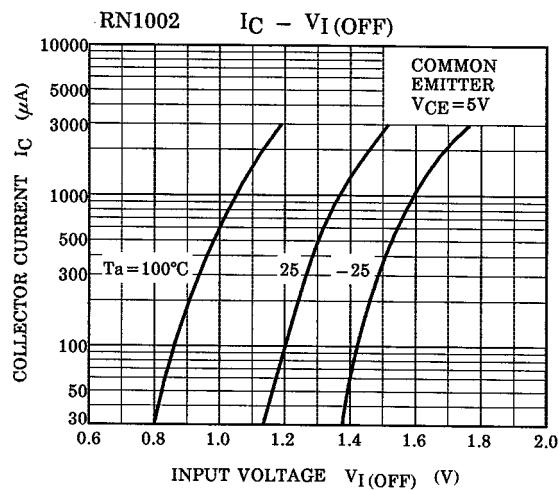
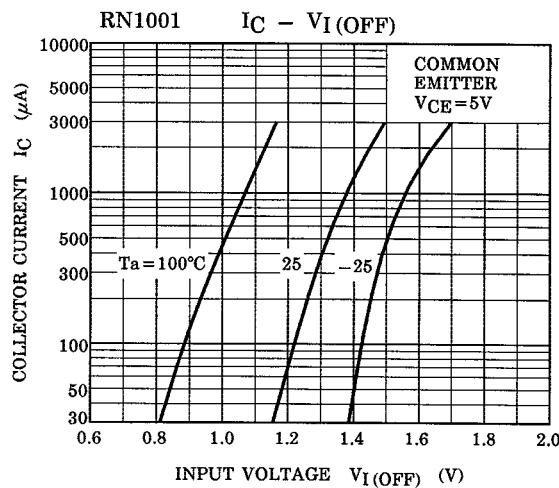
Weight: 0.21g

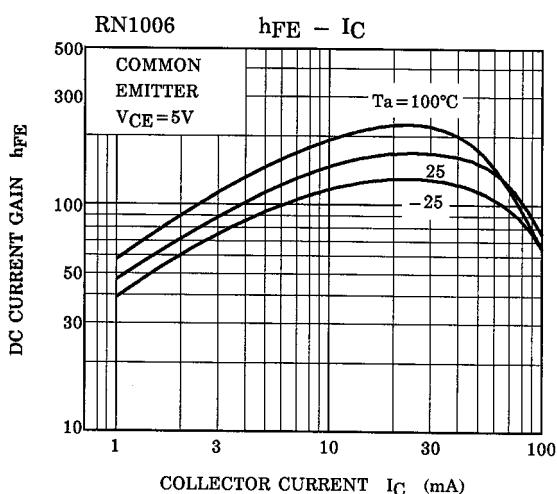
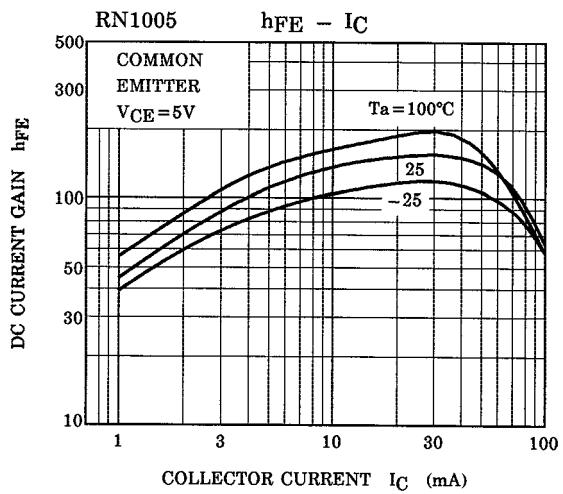
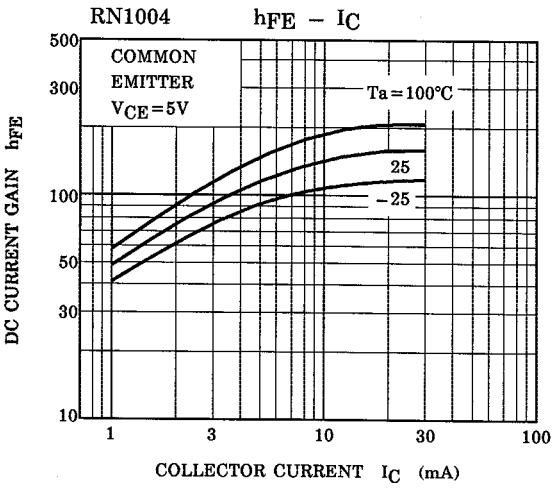
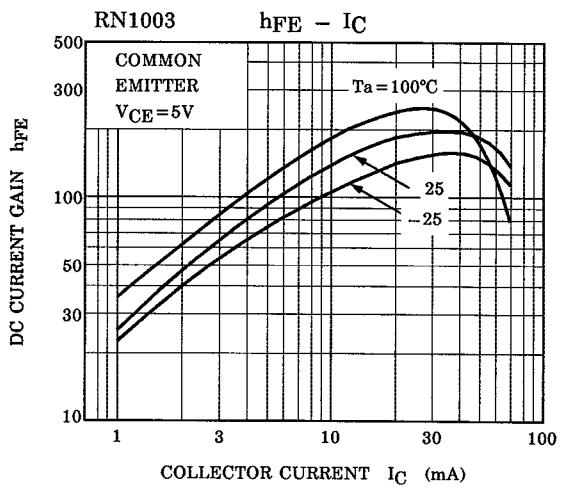
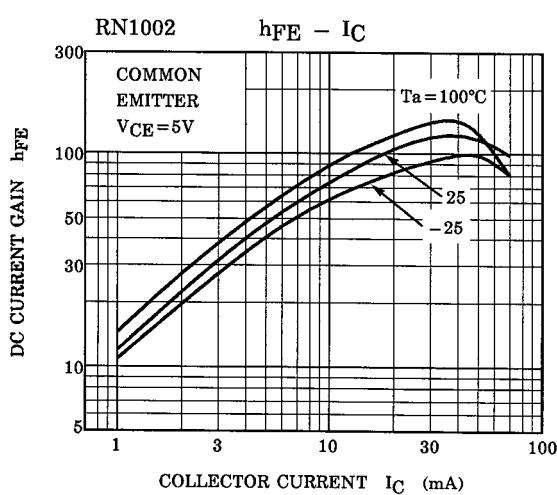
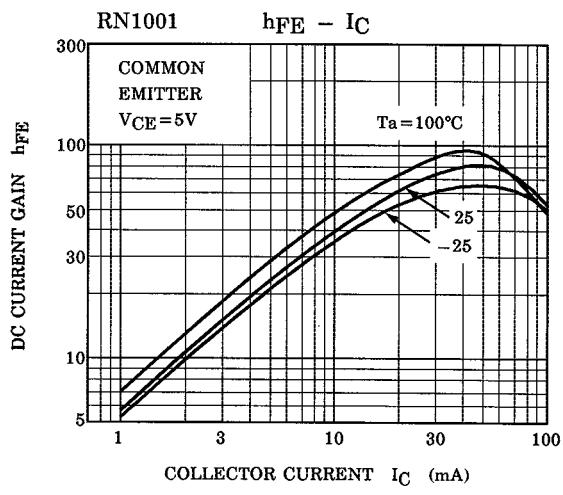
Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN1001~1006	V _{CBO}	50	V
Collector-emitter voltage		V _{CEO}	50	V
Emitter-base voltage	RN1001~1004 RN1005, 1006	V _{EBO}	10	V
			5	
Collector current	RN1001~1006	I _C	100	mA
Collector power dissipation		P _C	400	mW
Junction temperature		T _j	150	°C
Storage temperature range		T _{stg}	-55~150	°C

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1001~1006	I _{CBO}	—	V _{CB} = 50V, I _E = 0	—	—	100	nA
		I _{CEO}		V _{CE} = 50V, I _B = 0	—	—	500	
Emitter cut-off current	RN1001	I _{EBO}	—	V _{EB} = 10V, I _C = 0	0.82	—	1.52	mA
	RN1002				0.38	—	0.71	
	RN1003				0.17	—	0.33	
	RN1004				0.082	—	0.15	
	RN1005			V _{EB} = 5V, I _C = 0	0.078	—	0.145	
	RN1006				0.074	—	0.138	
DC current gain	RN1001	h _{FE}	—	V _{CE} = 5V, I _C = 10mA	30	—	—	—
	RN1002				50	—	—	
	RN1003				70	—	—	
	RN1004				80	—	—	
	RN1005				80	—	—	
	RN1006				80	—	—	
Collector-emitter saturation voltage	RN1001~1006	V _{CE} (sat)	—	I _C = 5mA, I _B = 0.25mA	—	0.1	0.3	V
Input voltage (ON)	RN1001	V _I (ON)	—	V _{CE} = 0.2V, I _C = 5mA	1.1	—	2.0	V
	RN1002				1.2	—	2.4	
	RN1003				1.3	—	3.0	
	RN1004				1.5	—	5.0	
	RN1005				0.6	—	1.1	
	RN1006				0.7	—	1.3	
Input voltage (OFF)	RN1001~1004	V _I (OFF)	—	V _{CE} = 5V, I _C = 0.1mA	1.0	—	1.5	V
	RN1005, 1006				0.5	—	0.8	
Transition frequency	RN1001~1006	f _T	—	V _{CE} = 10V, I _C = 5mA	—	250	—	MHz
Collector Output capacitance	RN1001~1006	C _{ob}	—	V _{CB} = 10V, I _E = 0, f = 1MHz	—	3	6	pF
Input resistor	RN1001	R1	—		3.29	4.7	6.11	kΩ
	RN1002				7	10	13	
	RN1003				15.4	22	28.6	
	RN1004				32.9	47	61.1	
	RN1005				1.54	2.2	2.86	
	RN1006				3.29	4.7	6.11	
Resistor ratio	RN1001~1004	R1/R2	—		0.9	1.0	1.1	—
	RN1005				0.0421	0.0468	0.0515	
	RN1006				0.09	0.1	0.11	







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